RAD-HARD ICs IN PLASTIC PACKAGES



Optimized solution for LEO constellation mission profile



Rad-hard analog and power management ICs in plastic packages offer a lightweight, cost-effective solution for LEO satellite constellations

Leveraging over 45-year of space heritage and automotive-grade AEC-Q100 qualified production lines, ST expands its series of radiation-hardened power, analog and logics ICs in plastic packages tailored for the "Low Earth Orbit" (LEO) satellites market.

Compliant with ST's LEO generic specification for ICs, these space-ready and automotive quality-based products offer an optimal balance of footprint size reduction, cost efficiency, quality assurance, radiation hardness, and high-volume manufacturing capability.

Available products for new-space V-reg POL N-FEF OUT REF OUT REF Logic ICs

BENEFITS

- Low cost of ownership
- Radiation proven
- Dedicated qualification level, screening and traceability
- Large quantity capacity
- Small packages with NiPdAu finishing
- AEC-Q100 based
- Single plant source

Specificities of new LEO ICs

Quality assurance	Radiation hardness		
 AEC-Q100 based framework Statistical process control Guaranteed single plant source "ST-LEO-Generic-Specification for ICs" 	TID up to 50 krad(Si) High dose rate (HDR) 40 krad(Si)/h Low dose rate (LDR) 10 mrad(Si)/s TNID @ 3.10 ¹¹ proton/cm ² SEL-free guaranteed at 62.5 MeV.cm ² /mg SET characterized up to 62.5 MeV.cm ² /mg		
Generic characteristics	Product versions		
 Plastic package with gold wires and NiPdAu finishing (whisker free) Space compliant outgassing (RML recovery mass loss < 1%, CVM collected volatile condensable material < 0.1%) Tested at 3 temperatures: -40/+25/+125°C 	Dummy samples: worst case final packaging for mounting qualification Development samples: evaluation and development Flight models: compliant with "ST-LEO-Generic-Specification for ICs"		

New available LEO ICs, compliant with "ST-LEO-Generic-Specification for ICs"

V-Reg	Description	Radiation	Vcc (V)	Drop voltage	Temp (°C)	
LE03910	2 A positive low drop voltage regulator	TID (HDR, LDR)	Vdrop 350 mV (at 400 mA)	40.1 405		
LEOPOL1	5 A step-down converter	TNID 3 to 12 SEL and SET		Current sharing	-40 to +125	
ADC	Description	Radiation	Vcc (V)	lcc max.	Temp (°C)	
LEOAD128	8-Channel 1Msps 12-bit ADC, with 8-input MUX	TID (HDR) SEL	2.7 to 3.6	2 mA (at 1Msps clock)	-40 to +125	
LVDS	Description	Radiation	Vcc (V)	Prop. delay (ns)	Temp (°C)	
LEOLVDSRD	LVDS driver-receiver, 400 Mbps	TID (HDR) SEL	3 to 3.6	1.5/2.5 (D/R)	-40 to +125	
Logics	Description	Radiation	Vcc (V)	Prop. delay (ns)	Temp (°C)	
LEOACOO	Quad 2-input NAND gate					
LEOAC08	Quad 2-input AND gate					
LEOAC14	Hex inverter	TID (HDR) SEL	0 to 6	0	40 to . 105	
LEOAC32	Quad 2-input OR gate		2 to 6	8	-40 to +125	
LEOAC74	Dual D-type flip-flop					
LEOAC244	Octal bus buffer					

Ordering information

Order code	Package	Quality level
LEOAD128PT-D	TSSOP-20	Development sample
LEOLVDSRDPT-D		
LEOACOOPT-D		
LEOACO8PT-D		
LEOAC14PT-D		
LEOAC32PT-D		
LEOAC74PT-D		
LEOAC244PT-D		

Order code	Package	Quality level
LE03910PDT	PowerSO-20	Flight model
LEOPOL1PDT	PowerSO-36	
LEOAD128PT		
LEOLVDSRDPT	TSSOP-20	
LEOACOOPT		
LEOAC08PT		
LEOAC14PT		
LEOAC32PT		
LEOAC74PT		
LEOAC244PT		

Note: LE03910 and LE0P0L1 samples are orderable through flight model order code $% \left(1\right) =\left(1\right) \left(1\right) \left$



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